

AlGaAs Infrared Laser Diode

ADL-85301TL
6-2D-LD85-008 Rev.00

850nm 30mW 5.6 φ TO-Type Laser Diode

• Features

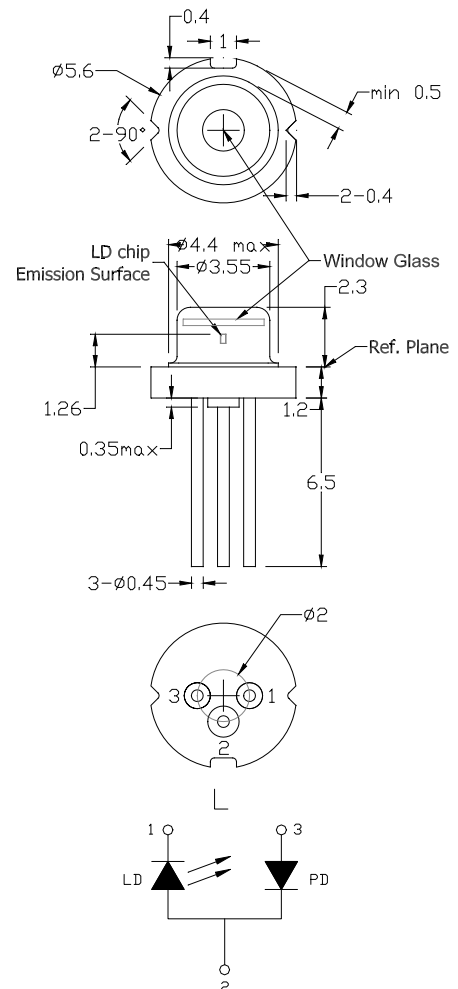
1. Low operation current
2. Cost effective

• Applications

1. Bar-code scanner
2. Laser printer
3. Military

• Absolute maximum ratings

Parameter	Symbol	Condition	Rating	Unit
Light output power	P_O	CW	30	mW
Reverse voltage (LD)	V_{RL}	-	3.5	V
Reverse voltage (PD)	V_{RD}	-	30	V
Forward current (PD)	I_{FD}	-	10	mA
Case temperature	T_C	-	-10~+50	°C
Storage temperature	T_S	-	-40~+85	°C



• Electrical and optical characteristics ($T_c=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Peak wavelength	λ	830	845	850	nm	$P_o=30\text{mW}$
Threshold current	I_{th}	-	15	25	mA	
Operating current	I_{op}	-	50	70	mA	$P_o=30\text{mW}$
Operating voltage	V_{op}	-	1.8	2.4	V	$P_o=30\text{mW}$
Differential efficiency	η	0.9	0.9	1.0	mW/mA	$P_o=20\text{-}30\text{mW}$
Monitor current	I_m	0.1	0.3	0.6	mA	$P_o=30\text{mW}, V_{RP}=5\text{V}$
Parallel divergence angle	$\theta_{ }$	7	11	15	degree	$P_o=30\text{mW}$
Perpendicular divergence angle	θ_{\perp}	26	30	35	degree	
Parallel FFP deviation angle	$\Delta\theta_{ }$	-3	-	+3	deg	
Perpendicular FFP deviation angle	$\Delta\theta_{\perp}$	-3	-	+3	deg	
Emission point accuracy	$\Delta x \Delta y$	-80	-	+80	um	
	ΔZ	-40	-	+40	um	

• Precautions

- * Do not operate the device above maximum ratings. Doing so may cause unexpected and permanent damage to the device.
- * Take precautions to avoid electrostatic discharge and/or momentary power spikes. A change in the characteristics of the laser or premature failure may result.
- * Proper heat sinking of the device assures stability and lifetime. Always ensure that maximum operating temperatures are not exceeded.
- * Observing visible or invisible laser beams with the human eye directly, or indirectly, can cause permanent damage. Use a camera to observe the laser.
- * No laser device should be used in any application or situation where life or property is at risk in event of device failure.
- * Specifications are subject to change without notice. Ensure that you have the latest specification by contacting us prior to purchase or use of the product.

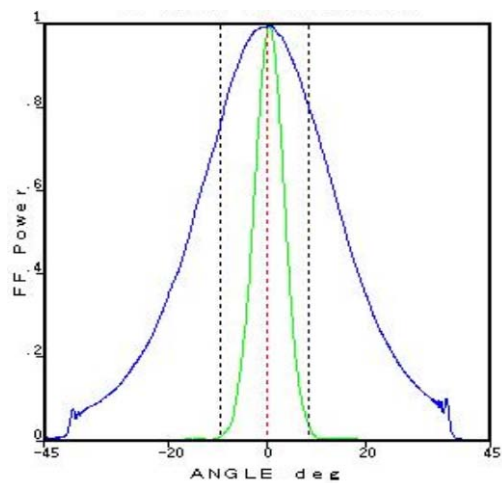
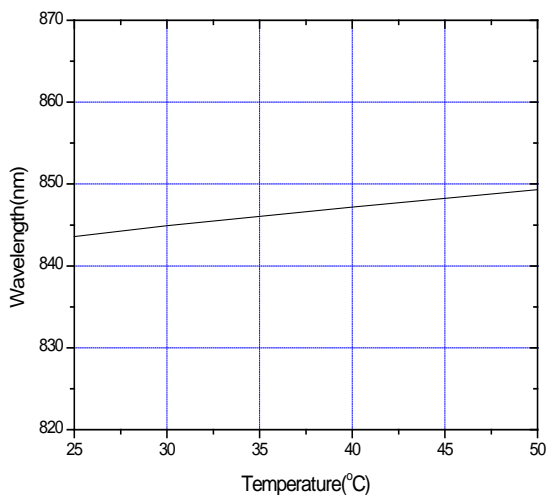
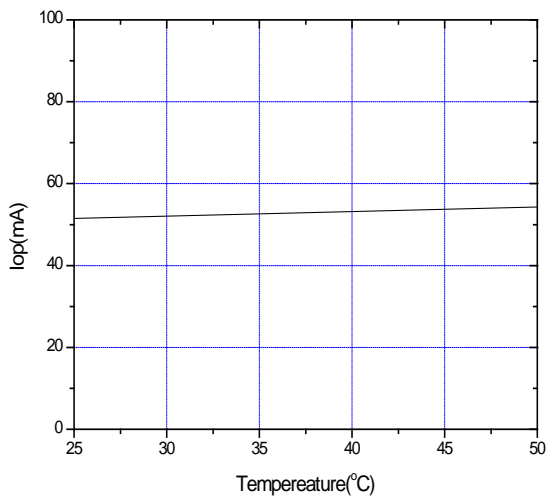
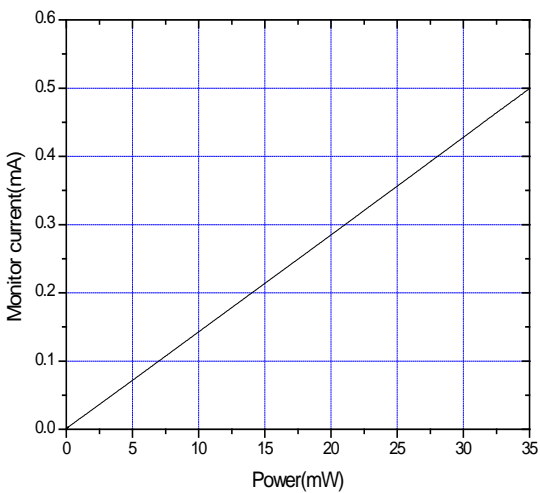
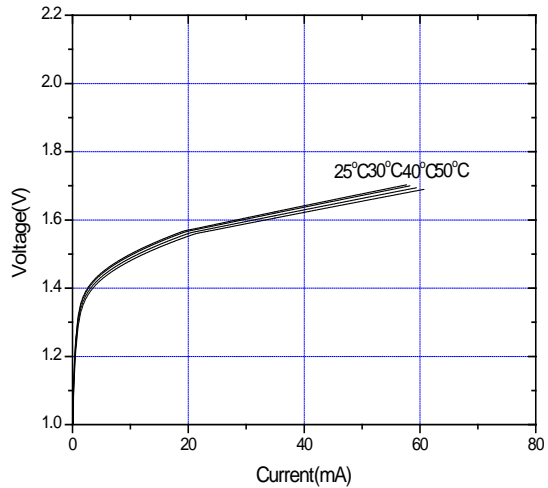
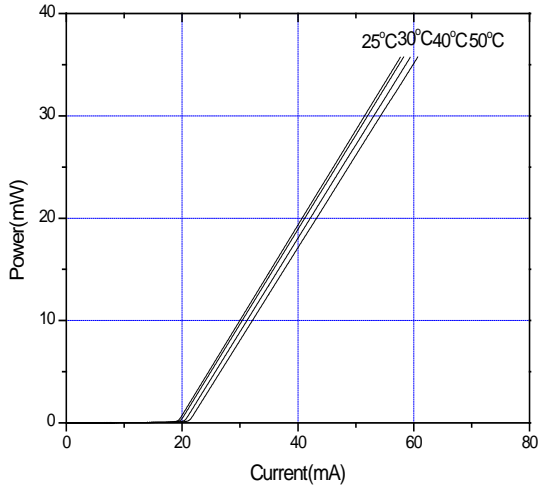
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